



DMT6006LK3

#### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I⊳ Max Tc = +25°C
60)/	6.5mΩ @ V <sub>GS</sub> = 10V	88A
60V	10mΩ @ V <sub>GS</sub> = 4.5V	73A

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) and maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

- Power Management Functions
- DC-DC Converters
- Backlighting

#### 60V N-CHANNEL ENHANCEMENT MODE MOSFET

#### Features

- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub> Minimizes Power Losses
- Low Q<sub>g</sub> –Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

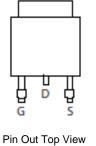
#### **Mechanical Data**

- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (£3)
- Weight: 0.33 grams (Approximate)

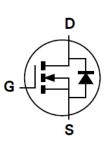


TO252 (DPAK)

Top View



D



Equivalent Circuit

#### Ordering Information (Note 4)

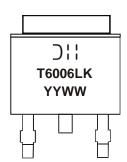
Part Number	Case	Packaging
DMT6006LK3-13	TO252 (DPAK)	2,500/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



) | | = Manufacturer's Marking
T6006LK = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 20 = 2020)
WW = Week Code (01 to 53)



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	60	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	Tc = +25°C Tc = +70°C	ID	88 71	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	350	A
Maximum Continuous Body Diode Forward Current (Note 6)	ls	88	A	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	lsм	350	A	
Avalanche Current, L = 0.1mH	las	28.5	A	
Avalanche Energy, L = 0.1mH		E <sub>AS</sub>	40.7	mJ

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	3.1	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	40	°C/W
Total Power Dissipation (Note 6)	T <sub>C</sub> = +25°C	PD	89.3	W
Thermal Resistance, Junction to Case (Note 6)	·	Rejc	1.4	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

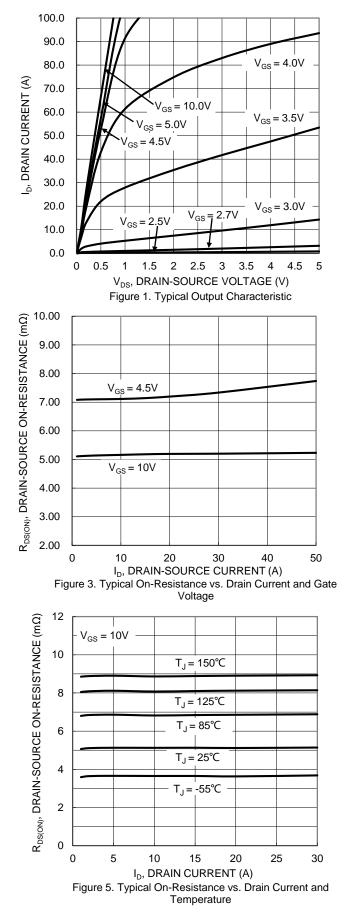
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	-	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)				•		·	
Gate Threshold Voltage	Vgs(th)	1.2	-	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Deserve	_	5.1	6.5		$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	Rds(on)		7.1	10	mΩ	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 10A	
Diode Forward Voltage	Vsd		0.8	1.2	V	$V_{GS} = 0V$ , $I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)			•			•	
Input Capacitance	Ciss		2162			$V_{DS} = 30V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	—	761	_	pF		
Reverse Transfer Capacitance	Crss	_	58	_			
Gate Resistance	Rg	_	0.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		18.1	_		V <sub>DD</sub> = 30V, I <sub>D</sub> = 20A	
Total Gate Charge (VGS = 10V)	Qg		34.9		nC		
Gate-Source Charge	Q <sub>gs</sub>		6.1	_	nc		
Gate-Drain Charge	Qgd		7.3	_			
Turn-On Delay Time	tD(ON)		6.0			$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-On Rise Time	t <sub>R</sub>		5.4				
Turn-Off Delay Time	tD(OFF)	_	20.4	_	ns	$I_D = 20A, R_g = 3\Omega$	
Turn-Off Fall Time	tF	—	7.8	_			
Reverse Recovery Time	trr	_	35.8	_	ns		
Reverse Recovery Charge	Qrr	_	40.2	_	nC	- I <sub>F</sub> = 20A, di/dt = 100A/μs	

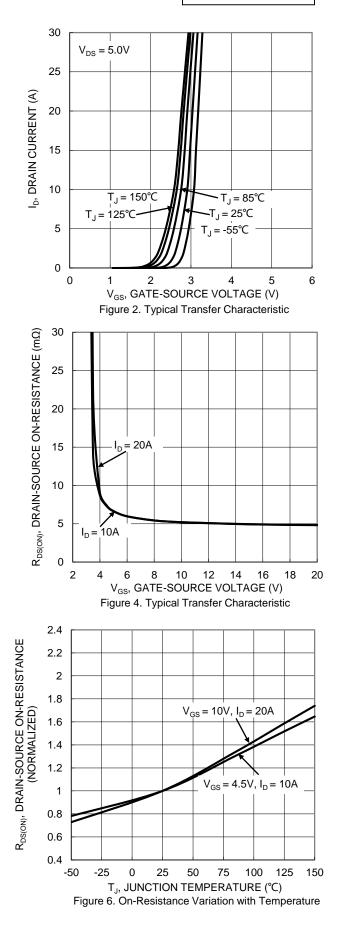
 Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



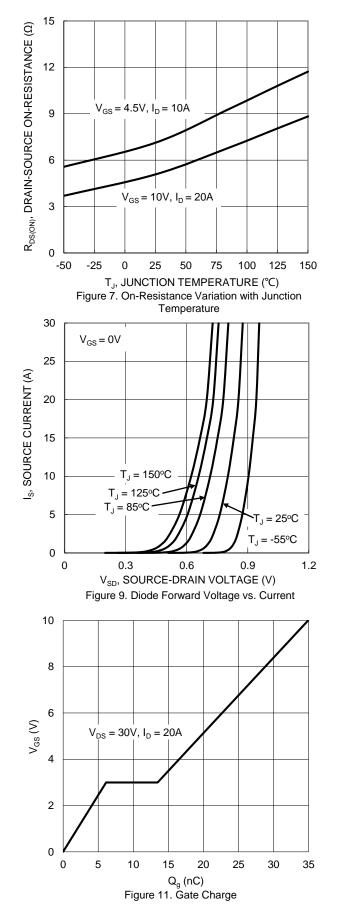
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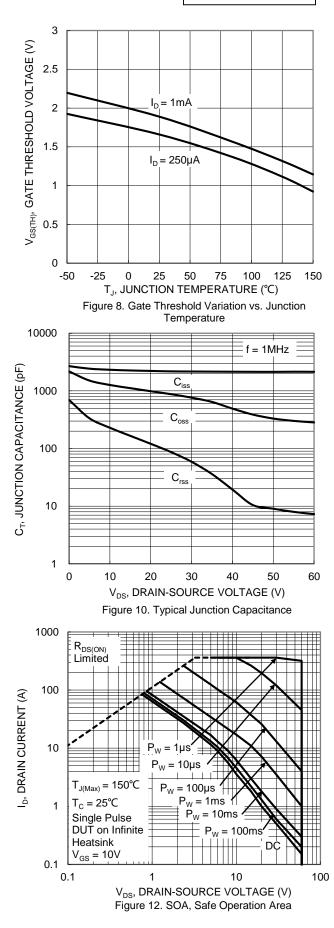




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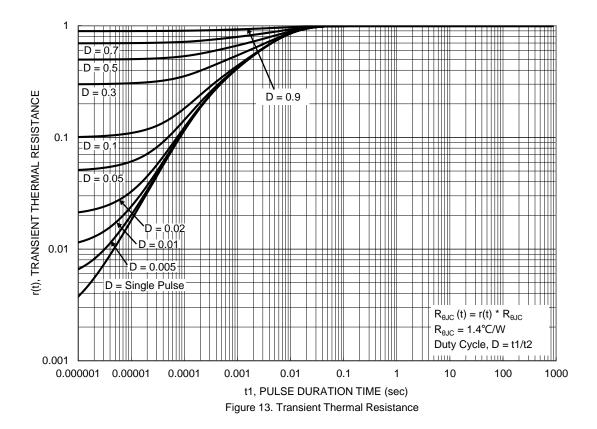






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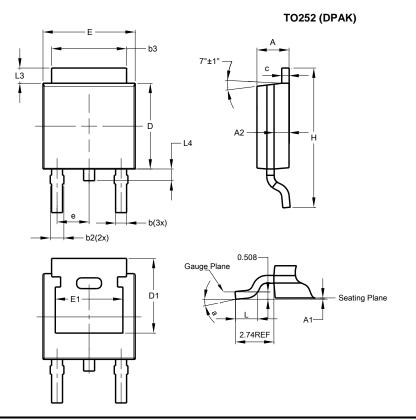






### **Package Outline Dimensions**

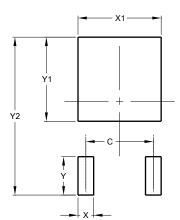
Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)						
Dim	Min	Max	Тур			
Α	2.19	2.39	2.29			
A1	0.00	0.13	0.08			
A2	0.97	1.17	1.07			
b	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
С	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21	-	-			
е	-	-	2.286			
Е	6.45	6.70	6.58			
E1	4.32	-	-			
Н	9.40	10.41	9.91			
L	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All Dimensions in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

#### TO252 (DPAK)



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